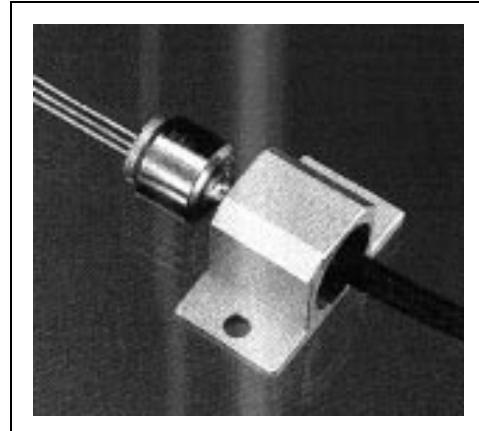


**Ge-Avalanche Photodiode with Pigtail,
Central Pin****SRD 00534X
SRD 00535X**

- Designed for application in fiber-optic communication systems
- Sensitive receiver for the 2nd optical window (1300 nm)
- High gain-bandwidth product
- Suitable for bit rates up to 2.5 Gbit/s and long-haul transmission
- Planar structure
- Small radiant sensitive area
- Low multiplied dark current
- High spectral sensitivity by built-in optics
- Hermetically sealed metal case with central pin
- With optimally coupled multimode-fiber pigtail



Type	Ordering Code	Connector/Flange
SRD 00534H	Q62702-Pxxxx	Pigtail, FC/PC-connector
SRD 00535H	Q62702-Pxxxx	Pigtail with flange, FC/PC-connector

Component with other connector types on request.**Maximum Ratings**

Parameter	Symbol	Values	Unit
Forward current	I_F	50	mA
Reverse voltage	V_R	*	V
Operating and storage temperature	$T_A T_{stg}$	- 40 ... + 85	°C
Max. radiant power into the opt. port ($V_R = 5$ V)	Φ_{port}	1	mW
Soldering time (wave / dip soldering), distance between solder point and base plate (≥ 2 mm, 260 °C)	t_s	10	s

* Individual value of V_{BR} is delivered with each component.

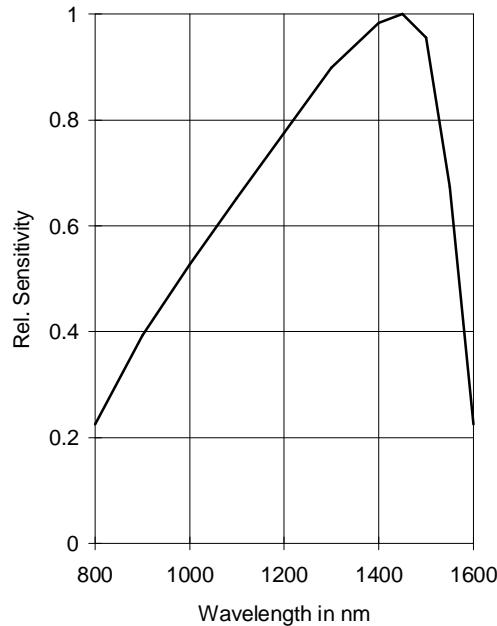
Characteristics

All optical data refer to an optimally coupled 10/125 μm SM fiber at ambient temperature of 25 °C, unless otherwise defined.

Parameter	Symbol	Values	Unit
Spectral sensitivity $\lambda = 1310 \text{ nm}$, $M = 1$	S_λ	0.8 (≥ 0.7)	A/W
Rise and fall time (10 % – 90 %) $R_L = 50 \Omega$, $M = 1$, $\lambda = 1310 \text{ nm}$, $\Phi_{\text{port}} = 100 \mu\text{W}$	$t_r; t_f$	0.3 (≤ 0.5)	ns
Multiplication factor at $V_R = 0.9 V_{BR}$	M	4 (≥ 3)	
Breakdown voltage $I_R = 100 \mu\text{A}$	V_{BR}	28 ... 40	V
Total capacitance, $\Phi_{\text{port}} = 0$, $f = 1 \text{ MHz}$ $V_R = 0 \text{ V}$, $V_R = 25 \text{ V}$	C	≤ 7 ≤ 1.5	pF pF
Dark current $V_R = 10 \text{ V}$ $V_R = 0.9 V_{BR}$	I_D	< 200 < 300	nA nA
Multiplied dark current ($M = 10$)	I_{DM}	≤ 20	nA
Optical return loss	R_L	> 30	dB

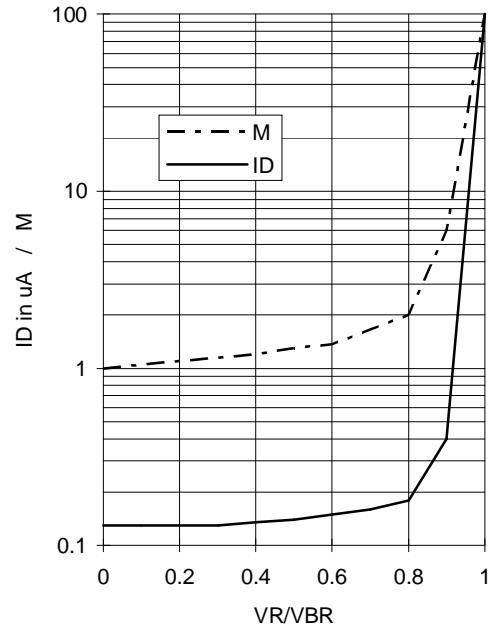
Rel. Spectral Sensitivity

$M = 1$ ($V_R = 10$ V)



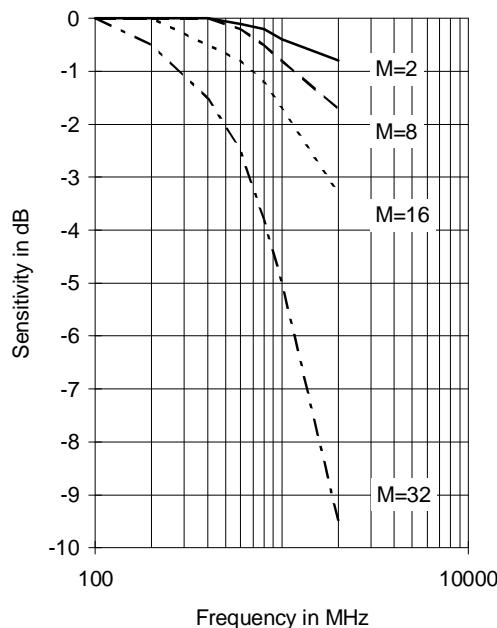
Dark Current $I_D = I_D(V_R / V_{BR})$

Multiplication Factor $M = M(V_R / V_{BR})$



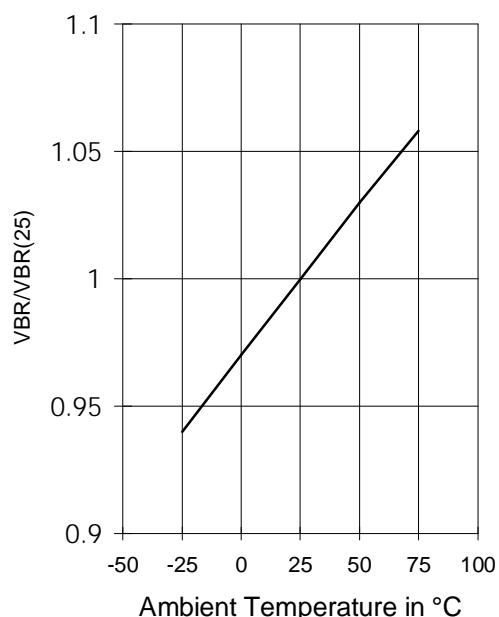
Frequency Response of Sensitivity

$S = S(f)$, $\lambda = 1300$ nm

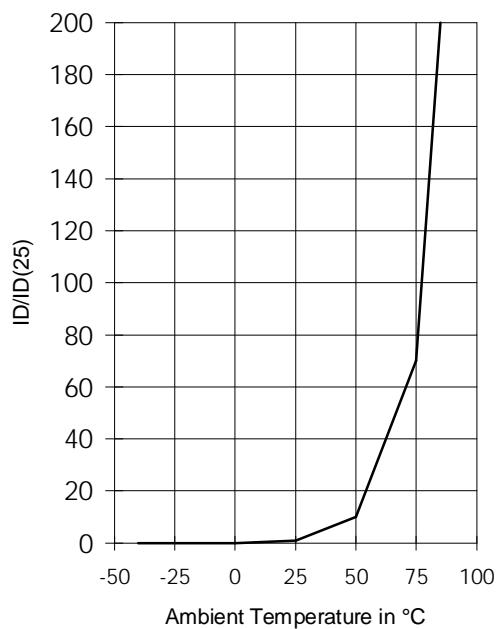


Temperatur Behaviour of Breakdown Voltage

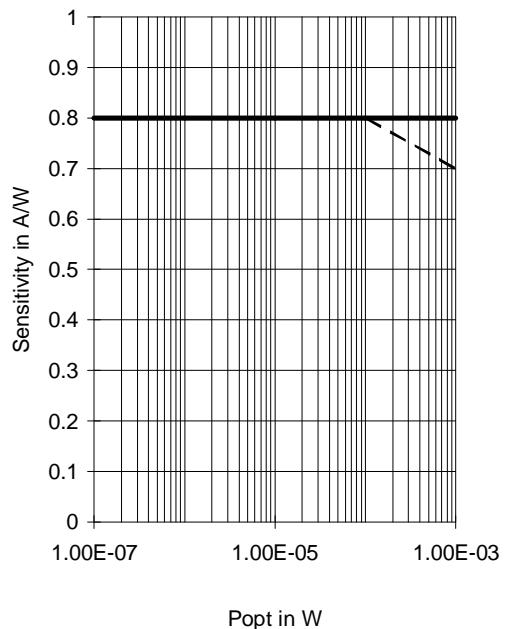
$V_{BR} / V_{BR(25\text{ }^{\circ}\text{C})}(T_A)$

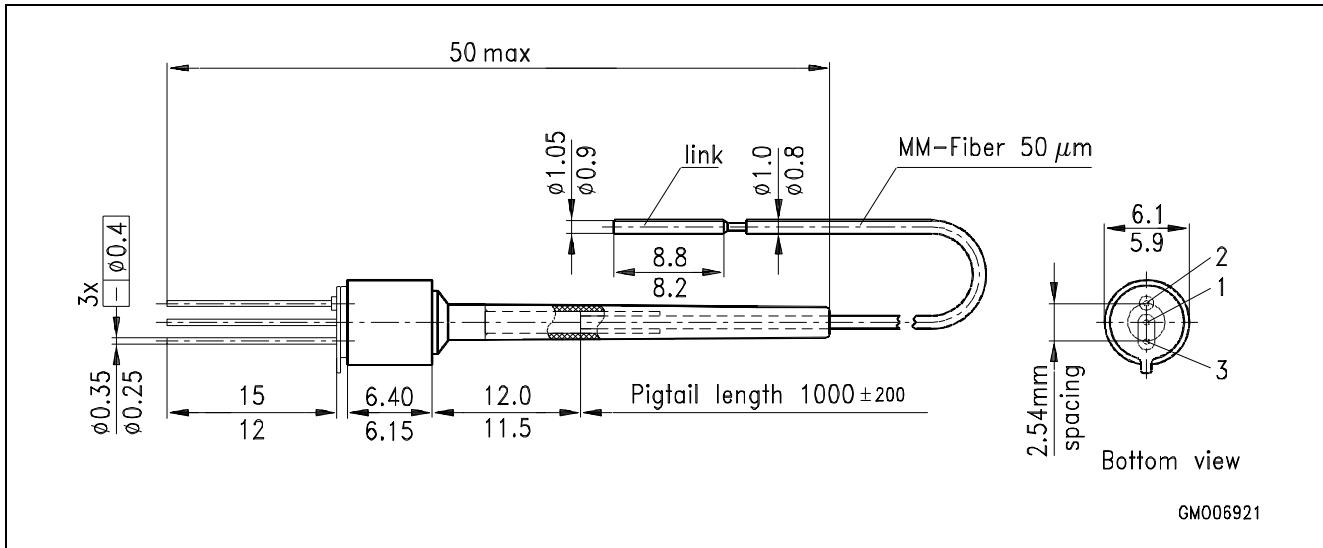
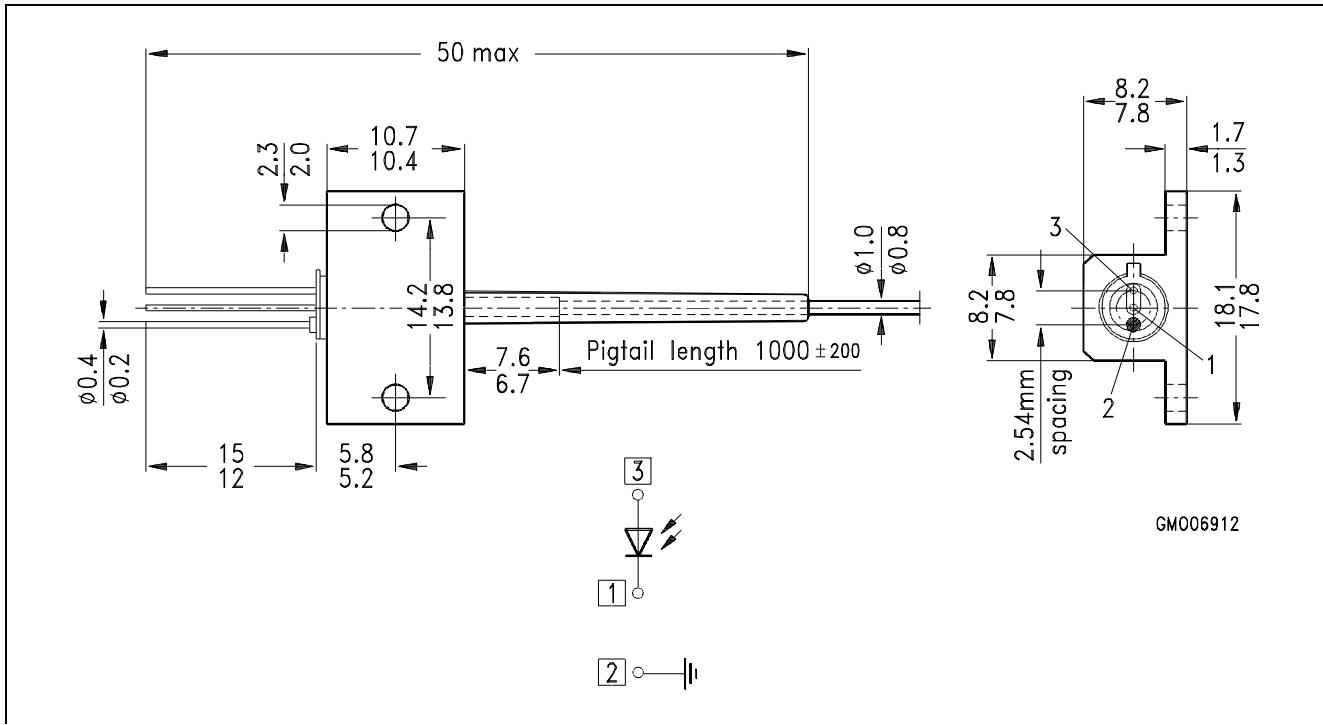


Temperature Behaviour of Dark Current
 $I_D / I_{D(25\text{ }^\circ\text{C})}(T_A)$



Sensitivity at different input Powers
 $V_{BR} / V_{BR(25\text{ }^\circ\text{C})}(T_A)$



Package Outlines (Dimensions in mm)**SRD 00534X****SRD 00535X**